

TSTE86 Homework 2: Solution

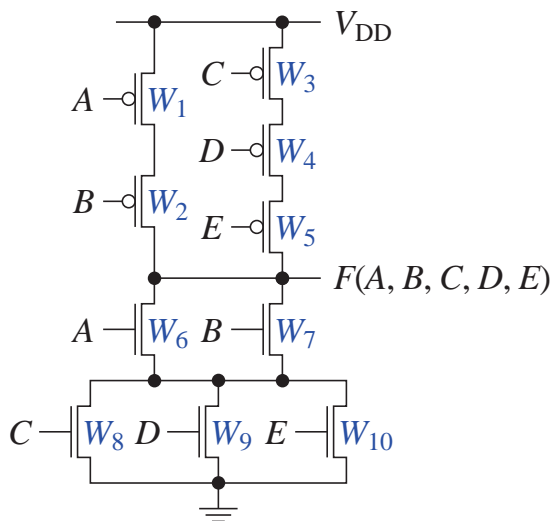
Identify logic function from gate schematic

$$F(A, B, C, D, E) = \overline{\overline{(A+B)} \cdot \overline{(C+D)} \cdot \overline{E}} = \overline{(A+B)(C+D+E)}$$

Switch nets

$$\begin{cases} S_p = F(\overline{A}, \overline{B}, \overline{C}, \overline{D}, \overline{E}) = \overline{\overline{(A+B)} \cdot \overline{(C+D+E)}} = AB + CDE \\ S_n = \overline{F(A, B, C, D, E)} = (A+B)(C+D+E) \end{cases}$$

Transistor schematic with annotated widths, W_k



Select all channel lengths to minimum, L_{\min} , and express the widths in units of L_{\min} . Worst case resistance occurs when a single path conducts. Design the widths of a single conduction path to be equal. Using $R \propto 1/W$, we should design the two pull-up paths to have an equivalent resistance of $W_p = 5L_{\min}$:

$$\begin{cases} \frac{1}{W_1} + \frac{1}{W_2} = \frac{1}{5} \\ \frac{1}{W_3} + \frac{1}{W_4} + \frac{1}{W_5} = \frac{1}{5} \end{cases} \xrightarrow{\text{equal widths in path}} \begin{cases} W_1 = W_2 = 10 \\ W_3 = W_4 = W_5 = 15 \end{cases}$$

Design the six pull-down paths to have an equivalent resistance of $W_n = 3L_{\min}$:

$$\begin{cases} W_6^{-1} + W_8^{-1} = 3^{-1} \\ W_6^{-1} + W_9^{-1} = 3^{-1} \\ W_6^{-1} + W_{10}^{-1} = 3^{-1} \\ W_7^{-1} + W_8^{-1} = 3^{-1} \\ W_7^{-1} + W_9^{-1} = 3^{-1} \\ W_7^{-1} + W_{10}^{-1} = 3^{-1} \end{cases} \xrightarrow{\text{equal widths in path}} \begin{cases} W_6 = W_8 = 6 \\ W_6 = W_9 = 6 \\ W_6 = W_{10} = 6 \\ W_7 = W_8 = 6 \\ W_8 = W_9 = 6 \\ W_9 = W_{10} = 6 \end{cases}$$

Hence $W_1 = W_2 = 10 L_{\min}$, $W_3 = W_4 = W_5 = 15 L_{\min}$, and $W_6 = W_7 = W_8 = W_9 = W_{10} = 6 L_{\min}$.